

Insulated Ultrafast Rectifier Module, 120 A


SOT-227

FEATURES

- Two fully independent diodes
- Ceramic fully insulated package ($V_{ISOL} = 2500 V_{AC}$)
- Ultrafast reverse recovery
- Ultrasoft reverse recovery current shape
- Low forward voltage
- Optimized for power conversion: welding and industrial SMPS applications
- Industry standard outline
- Plug-in compatible with other SOT-227 packages
- Easy to assemble
- Direct mounting to heatsink
- UL approved file E78996 
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level


RoHS
COMPLIANT

PRODUCT SUMMARY

V_R	600 V
$I_{F(AV)}$ per module at $T_C = 80^\circ C$	120 A
t_{rr}	96 ns

DESCRIPTION

The UFL120FA60P insulated modules integrate two state of the art Vishay Semiconductors ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness, and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be a predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, and dc-to-dc converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		600	V
Continuous forward current per diode	I_F	$T_C = 85^\circ C$	69	A
Single pulse forward current per diode	I_{FSM}	$T_C = 25^\circ C$	750	
Maximum power dissipation per module	P_D	$T_C = 85^\circ C$	180	W
RMS isolation voltage	V_{ISOL}	Any terminal to case, $t = 1 \text{ min}$	2500	V
Operating junction and storage temperatures	T_J, T_{Stg}		- 55 to 175	$^\circ C$

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	V_{FM}	$I_F = 60\text{ A}$	-	1.29	1.60	
		$I_F = 120\text{ A}$	-	1.49	1.88	
		$I_F = 60\text{ A}$	-	1.13	1.35	
		$I_F = 120\text{ A}$	-	1.37	1.68	
Reverse leakage current	I_{RM}	$V_R = V_R\text{ rated}$	-	0.1	100	μA
		$T_J = 175\text{ }^{\circ}\text{C}$, $V_R = V_R\text{ rated}$	-	0.2	1.0	mA
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	80	-	pF

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	96	141	ns
		$T_J = 125\text{ }^{\circ}\text{C}$	-	190	246	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^{\circ}\text{C}$	-	7	13	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	17	25	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	340	917	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	1581	3075	

$I_F = 50\text{ A}$
 $di_F/dt = 200\text{ A}/\mu\text{s}$
 $V_R = 200\text{ V}$

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	R_{thJC}		-	-	1.0	$^{\circ}\text{C}/\text{W}$
Junction to case, both leg conducting			-	-	0.5	
Case to heatsink	R_{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	N · m

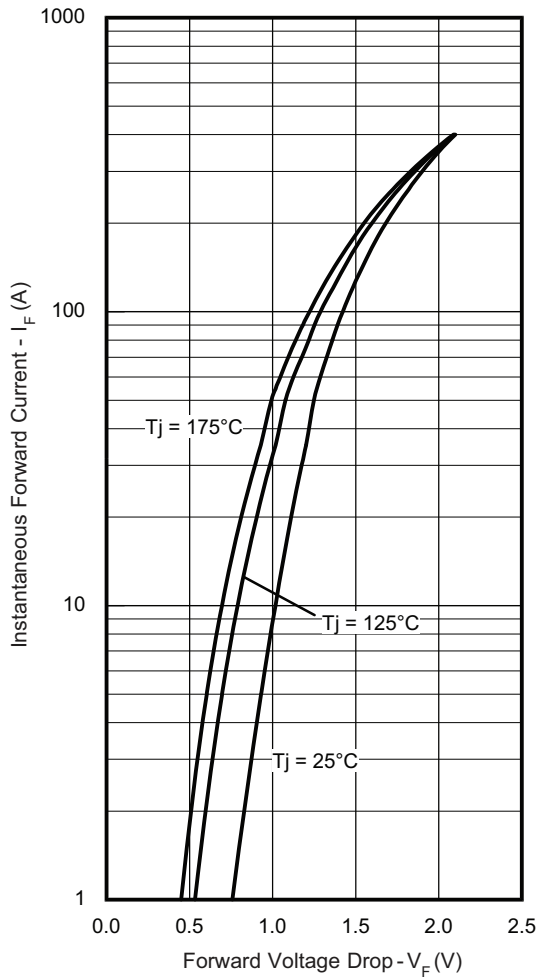


Fig. 1 - Typical Forward Voltage Drop Characteristics (Per Diode)

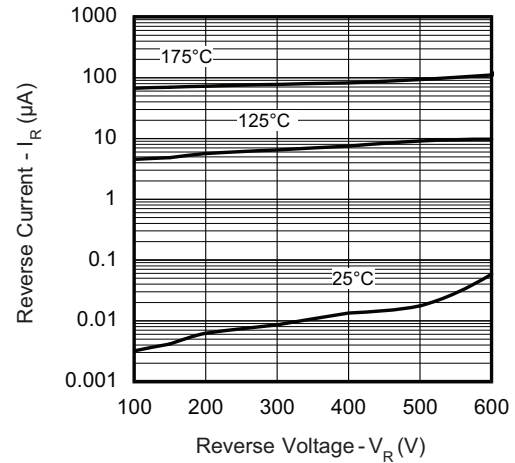


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

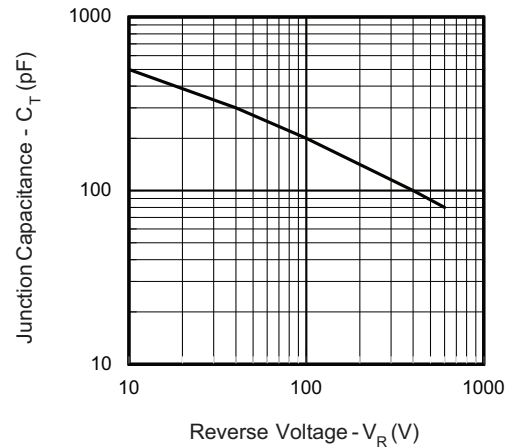


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

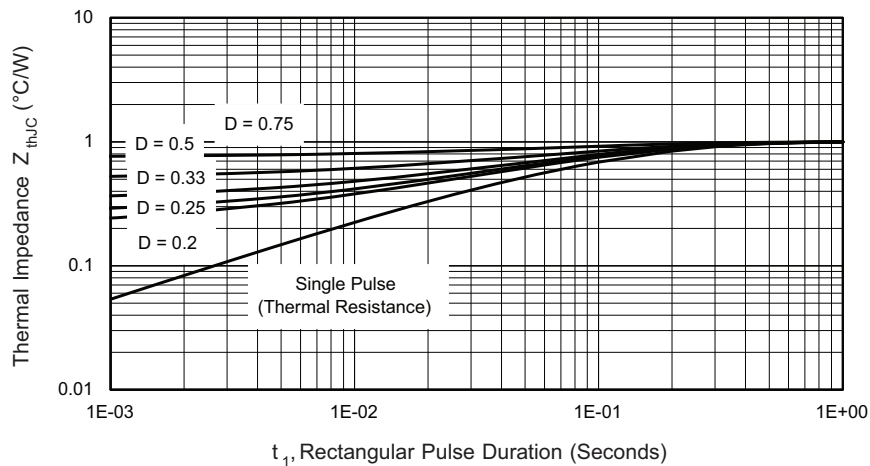


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

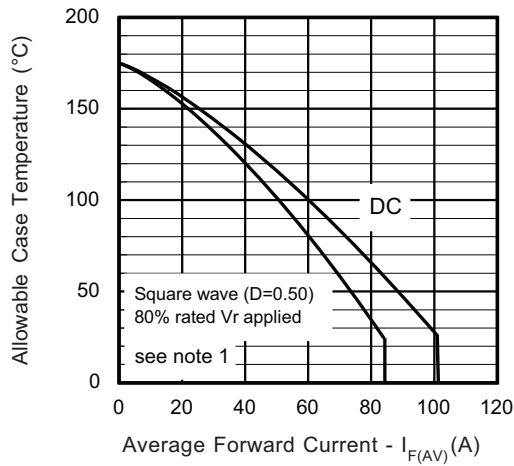


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

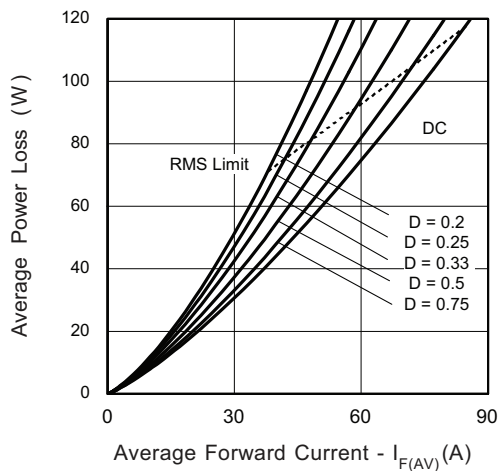


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

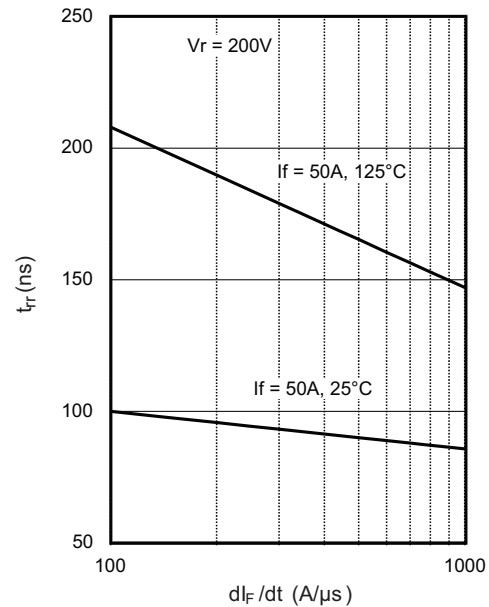


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

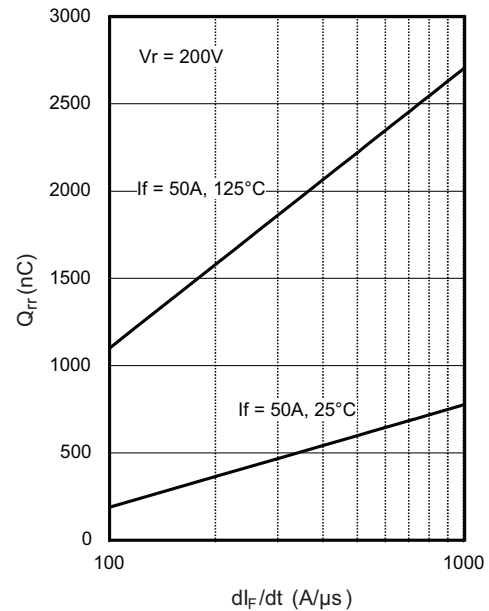


Fig. 8 - Typical Stored Charge vs. dI_F/dt

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

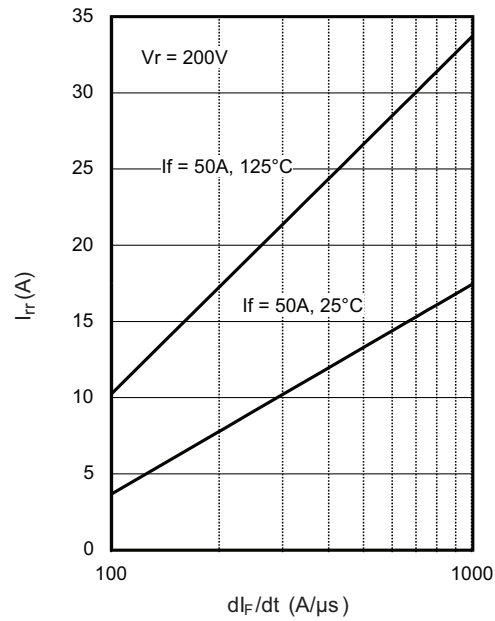
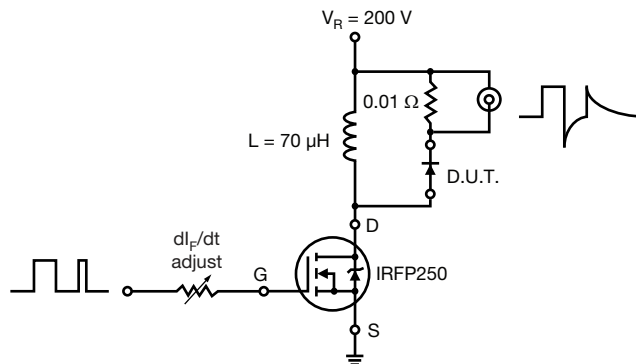

 Fig. 9 - Typical Stored Current vs. di_F/dt


Fig. 10 - Reverse Recovery Parameter Test Circuit

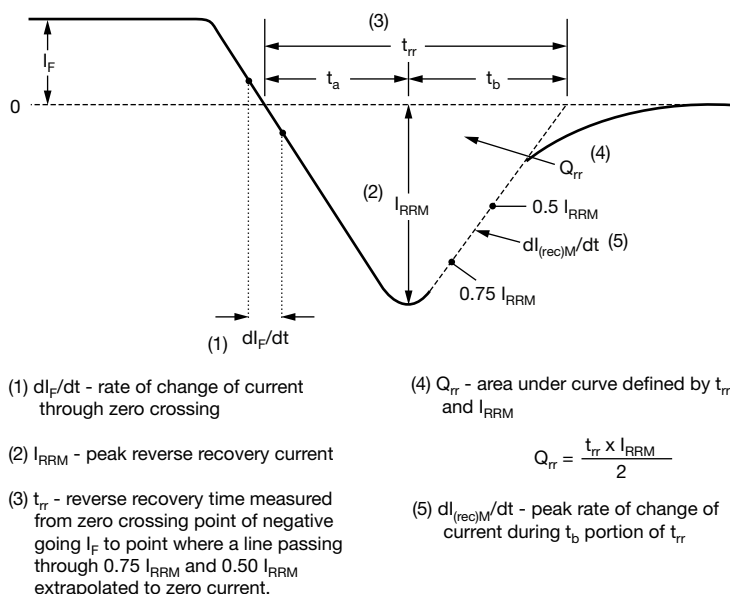
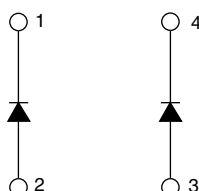


Fig. 11 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	UF	L	120	F	A	60	P
	1	2	3	4	5	6	7
1	Ultrafast rectifier						
2	Ultrafast Pt low V_F						
3	Current rating (120 = 120 A)						
4	Circuit configuration (2 separate diodes, parallel pin-out)						
5	Package indicator (SOT-227 standard isolated base)						
6	Voltage rating (60 = 600 V)						
7	P = Lead (Pb)-free						

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95036
Packaging information	www.vishay.com/doc?95037



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